ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

FPF2411 — IntelliMAX[™] 6 V / 6 A - Rated Bi-Directional Switch with Slew Rate Control and RCB

Features

- Capability: 6 V
- Low Ron
 - 10 mΩ at 5 V at PWRA or PWRB (Typ.)
 - 12 mΩ at 3.8 V at PWRA or PWRB (Typ.)
- Maximum Current Capability: 6 A (Bi-Directional)
- Ultra-Low l_Q:<1 µA
- Active LOW Control Pin
- 2 ms Long Slew Rate
- Reverse Current Blocking (RCB) during OFF
- Robust ESD Capability:
 - 5 kV HBM, 2 kV CDM
 - 15 kV Air Discharge
 - 8 kV Contact Discharge Under IEC 61000-4-2

Applications

- Smartphone / Tablet PC
- Mobile Devices
- Portable Media Devices

Description

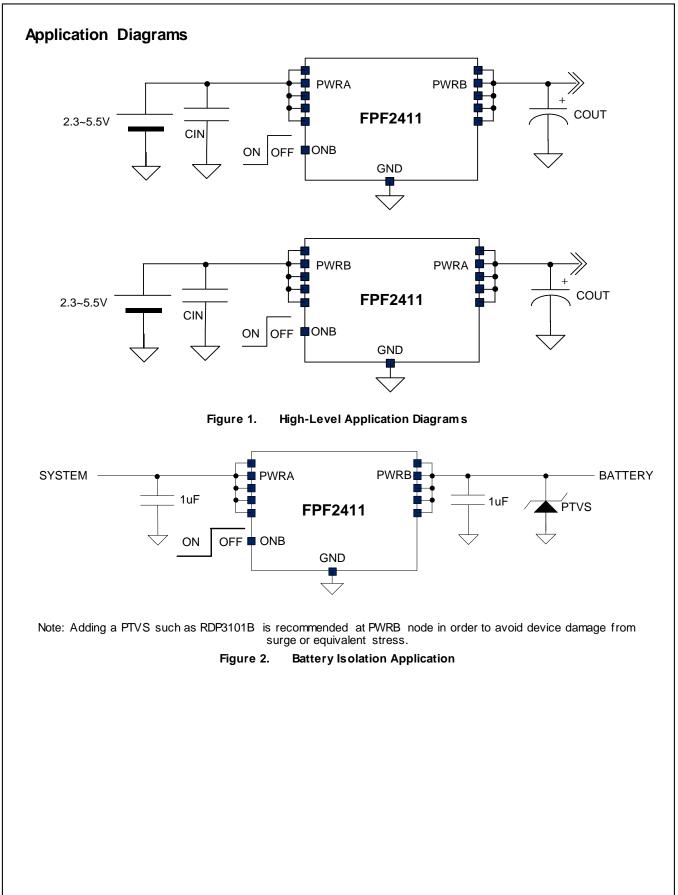
The FPF2411 is a 6 V / 6 A-rated bi-directional load switch, consisting of a slew-rate-controlled, low-on-resistance, P-channel MOSFET switch with protection features. The slew-rate-controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on the input pow er rails. The input voltage range operates from 2.3 V to 5.5 V.

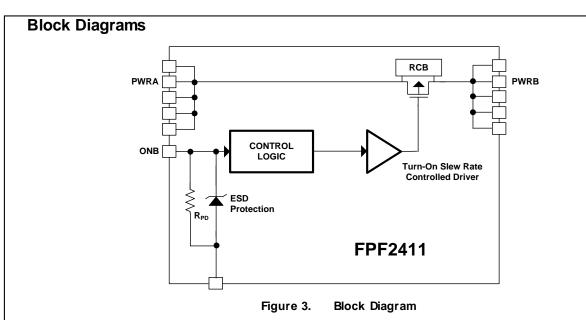
Bi-directional switching allows reverse current from V_{OUT} to V_{IN} . The switching is controlled by active-LOW logic input the ONB pin. The FPF2411 is capable of interfacing directly with low-voltage control signal General-Purpose Input / Output (GPIO).

The FPF2411 is available in 12-bump, 1.235 mm x 1.625 mm Wafer-Level Chip-Scale Package (WLCSP) with 0.4 mm pitch.

Ordering Information

Part Number	Top Mark	R _{oN} (Typ.) at 3.8 V _№	Output Discharge	ONB Pin Functionality	Package
FPF2411BUCX-F130	QR	12 mΩ	No	Active LOW	12-Ball Wafer-Level Chip-Scale Package (WLCSP), 3 x 4 Array, 0.4 mm Pitch, 250 µm Ball





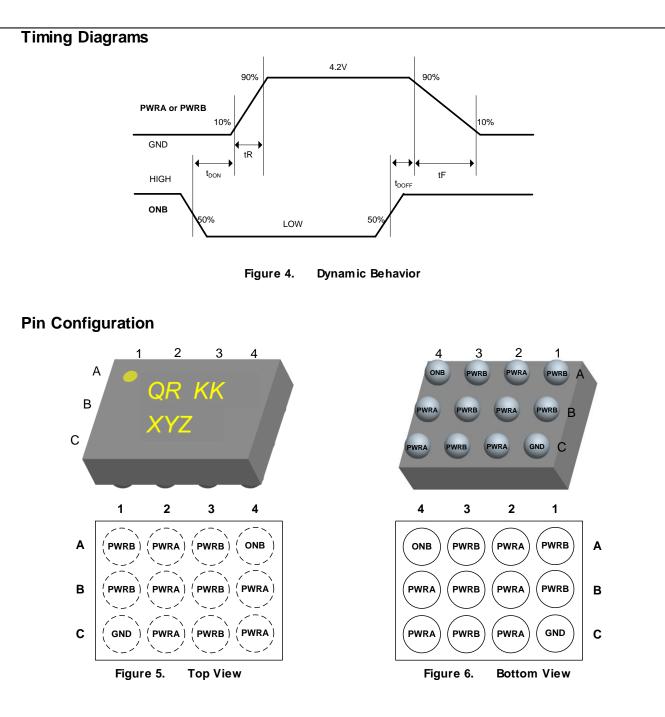
Application Scenario

Table 1.	PWRA and PWRB can be Input or Output, Depending on Scenario
----------	---

PWRA	PWRB	ONB	Operations		
Х	x	HIGH	OFF state PWRA and PWRB are isolated. Current more than I _{SD} or I _{RCB} is NOT allow ed.		
2.3~5.5 V	Open	HIGH \rightarrow LOW	Turn-on with 2 ms of t _R at PWRB.		
Open	2.3~5.5 V	HIGH \rightarrow LOW	Turn-on with 2 ms of t _R at PWRA.		
2.3~5.5 V	Open	LOW	ON state Operating current is from PWRA. No problem with 6 A DC current flow ing.		
Open	2.3~5.5 V	LOW	ON state Operating current is from PWRB. No problem with 6 A DC current flowing.		
2.3~5.5 V	Open	$LOW \rightarrow HIGH$	Turn-off with 1 ms of t _F at PWRB.		
Open	2.3~5.5 V	$LOW \rightarrow HIGH$	Turn-off with 1 ms of t _F at PWRA.		

Note:

1. X = Don't care.



Pin Descriptions

Pin #	Name	Description
A2, B2, B4, C2, C4	PWRA	Pow er Input / Output: Bi-directional pow er path
A1, A3, B1, B3, C3	PWRB	Pow er Input / Output: Bi-directional pow er path
C1	GND	Ground
A4	ONB	ON/OFF Control Input: Active LOW.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter				
V _{PIN}	PWRA, PWRB, ONB to GND		-0.3	6.0	V	
Isw	Maximum Continuous Switch	Maximum Continuous Switch Current				
t _{PD}	Total Power Dissipation at T_A		1.48	W		
TJ	Operating Junction Temperate	ure	-40	+150	°C	
T _{STG}	Storage Junction Temperature	9	-65	+150	°C	
ΘJA	Thermal Resistance, Junction	-to-Ambient (1in. ² Pad of 2 oz. Copper)		84.1 ⁽²⁾	°C/W	
	Electrostatic Discharge	Human Body Model, JESD22-A114	5			
ESD	Capability	Charged Device Model, JESD22-C101	2		kV	
100	IEC61000-4-2 System Level	Air Discharge (PWRA, PWRB, ONB to GND)	15		Ň	
		Contact Discharge (PWRA, PWRB, ONB to GND)	8			

Note:

2. Measured using 2S2P JEDEC std. PCB.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. On Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Max.	Unit
V _{PWRn}	PWRA, PWRB	2.3	5.5	V
TA	Ambient Operating Temperature	-40	85	°C

DC / AC Characteristics

Unless otherwise noted, V_{IN}=2.3 to 5.5 V, T_A=-40 to 85°C; typical values are at PWRA or PWRB=4.2 V and T_A=25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Vpwra Vpwrb	Input Voltage		2.3		5.5	V
Isd	Shutdow n Current	PWRA=ONB=5.5 V, PWRB=Open OR PWRB=ONB=5.5 V, PWRA=Open			1	μA
IPWRA IPWRB	Quiescent Current	ONB=GND, IOUT=0 mA			1	μA
Ron	On-Resistance	PWRA, PWRB=3.8 V, I _{OUT} =200 mA, T _A =25°C	12 17		mΩ	
RON	On-Resistance	PWRA, PWRB=5 V, I_{OUT} =200 mA, T _A =25°C		10	16	1162
VIH	ONB, Input Logic HIGH Voltage ⁽³⁾	PWRn=4.5 V, I_{LOAD} =50 μ A, T_A (Max.) = 60°C	4.3			
V IH		PWRn=3.6 V, I_{LOAD} =50 μ A, T _A (Max.) = 60°C	3.4			V
VIL	ONB, Input Logic LOW Voltage ⁽³⁾	PWRn=4.5 V, I_{LOAD} =50 μ A, T _A (Max.) = 60°C			0.4	v
VIL		PWRn=3.6 V, I_{LOAD} =50 μ A, T _A (Max.) = 60°C			0.4	
R _{PD}	Pull-Down Resistance at ONB			500	700	kΩ
Dynamic	Characteristics: see definition	ons below				
t DON	Turn-On Delay ^(4,5,6)			1.5		
t _R	Rise Time ^(4,5,6)	PWRA or PWRB =4.2 V, R _L =10 Ω, C _L =1 μ F, ONB=HIGH to LOW		3.0		ms
t _{ON}	Turn-On Time ^(4,5,6)			4.5		
t DOFF	Turn-Off Delay ^(4,5,7)			5.5		
tF	Fall Time ^(4,5,7)	PWRA or PWRB =4.2 V, R _L =100 Ω, C _L =1 μ F, ONB=LOW to HIGH		1.0		ms
toff	Turn-Off Time ^(4,5,7)			6.5		

Notes:

3. V_{IH}/V_{IL} is tested under 50 μ A current load

4. This parameter is guaranteed by design and characterization; not production tested.

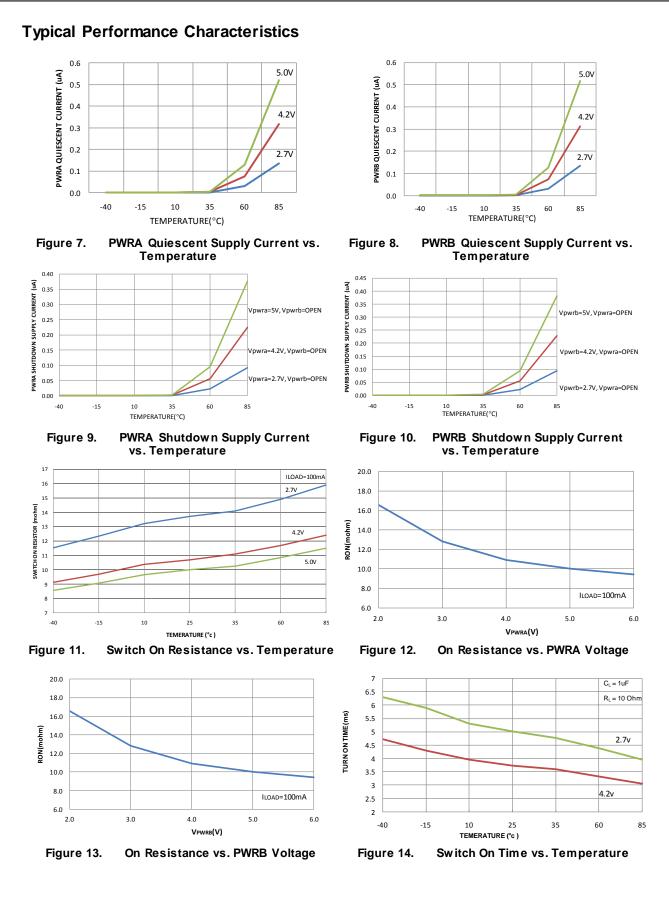
5. t_{DON}/t_{DOFF}/t_R/t_F are defined in Figure 4.

6. $t_{ON}=t_R + t_{DON}$.

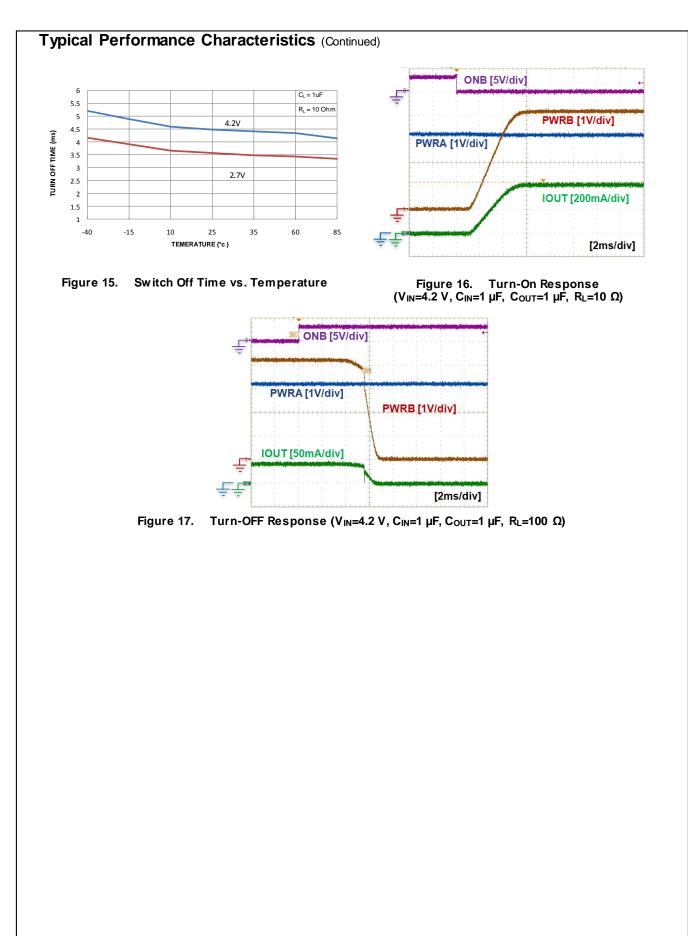
7. $t_{OFF}=t_F + t_{DOFF}$

Table 2. $V_{IH} / V_{IL} [V]$

I _{LOAD} \ V _{BAT}	2.7 V	3.7 V	4.35 V
0.1 mA	1.8 / 0.7	2.9 / 0.9	3.4 / 1.0
1 mA	1.1 / 0.7	2.1 / 0.9	2.8 / 1.0
3 mA	1.1 / 0.7	2.1 / 0.9	2.7 / 1.0
5 mA	1.0 / 0.7	2.0 / 0.9	2.7 / 1.0
10 mA	0.9 / 0.7	1.9 / 0.8	2.4 / 0.9
30 mA	0.9 / 0.7	1.5 / 0.8	2.2 / 0.9
50 mA	0.9 / 0.7	1.2 / 0.8	1.9 / 0.9
100 mA	0.9 / 0.7	1.0 / 0.8	1.1 / 0.9



FPF2411 — IntelliMAX[™] 6 V / 6 A-Rated Bi-Direction Switch with Slew-Rate Control



Operation and Application Description

The FPF2411 is an ultra-low -R_{ON} P-channel load switch with bi-directional controlled turn-on and Reverse Current Blocking (RCB). The core is a 12 m Ω P-channel MOSFET and controller capable of functioning over a wide input operating range of 2.3 V to 5.5 V. The ONB pin, active-LOW; controls the state of the switch. RCB functionality blocks unwanted reverse current during OFF states by power switch isolation between PWRA and PWRB.

Inrush Current

Inrush current occurs when the device is turned on. Inrush current is dependent on output capacitance and slew rate control capability, as expressed by:

$$I_{INRUSH} = C_{OUT} \times \frac{V_{IN} - V_{INITIAL}}{t_R} + I_{LOAD}$$

w here:

COUT: Output capacitance;

t_R: Slew rate or rise time at V_{OUT};

V_{IN}: Input voltage;

 V_{INITIAL} : Initial voltage at $C_{\text{OUT}},$ usually GND; and I_{LOAD} : Load current.

Higher inrush current causes higher input voltage drop, depending on the distributed input resistance and input capacitance. High inrush current can cause problems.

FPF2411 has a 3 ms of slew rate capability under 4.2 V_{IN} at 1 μ F of C_{OUT} and 10 Ω of R_L. Inrush current can be minimized and no input voltage drop appears, as show n in Figure 16.

Reverse-Current Blocking

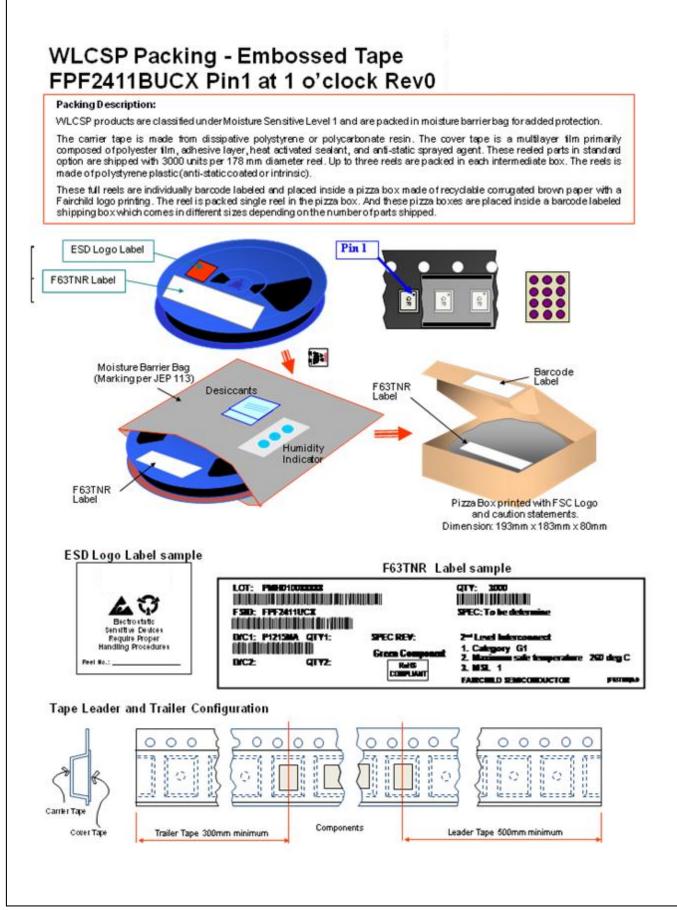
The reverse-current blocking feature protects the input source against current flow from output to input when the load switch is off by changing the internal body diode direction.

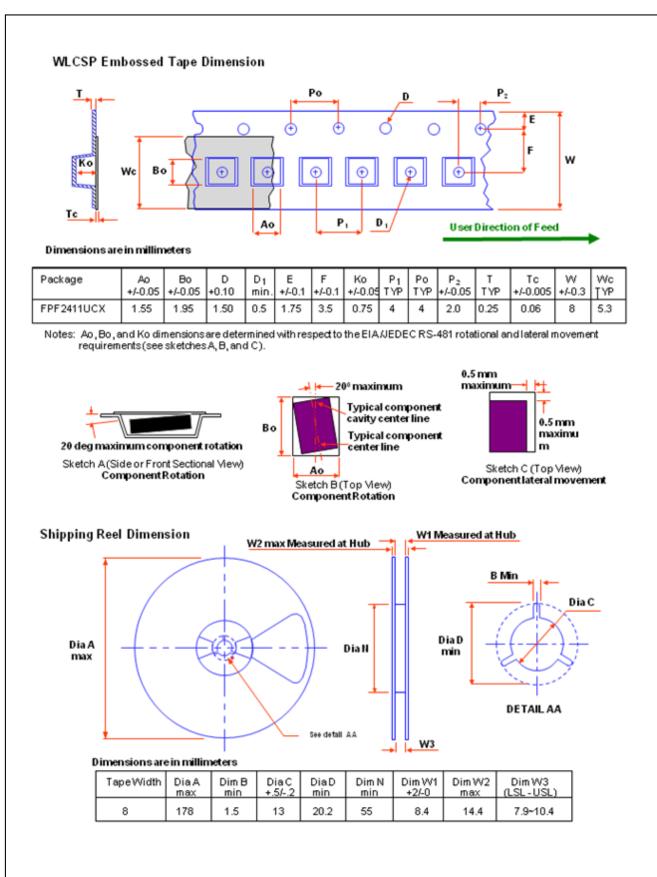
Bypass Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor; a capacitor must be placed betw een the PWRA or PWRB and GND pins. A ceramic capacitor of at least 1 μ F placed close to the pins is usually sufficient.

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (PWRA, PWRB, ONB, and GND) minimizes the parasitic electrical effects and the case-to-ambient thermal impedance.





Rev1,25102011

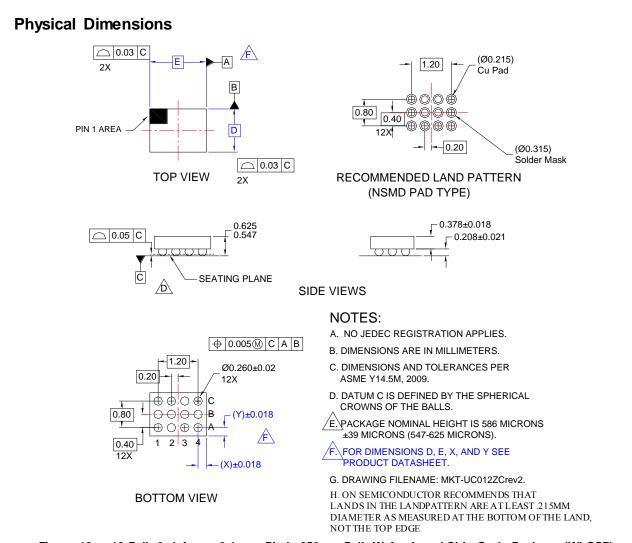


Figure 18. 12-Ball, 3x4 Array, 0.4 mm Pitch, 250 µm Ball, Wafer-Level Chip-Scale Package (WLCSP)

Nominal Values

Bump	Overall Package	Silicon	Solder Bump	Solder Bump
Pitch	Height	Thickness	Height	Diameter
0.4 mm	0.586 mm	0.378 mm	0.208 mm	

Product-Specific Dimensions

Product	D	E	Х	Y
FPF2411BUCX-F130	1.235 mm	1.625 mm	0.2125 mm	0.2175 mm

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage maybe accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the rights to rake changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor ata sheets and/or specifications can and do vary in different applications da actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products for any such unintended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its off

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. Amer ic an Technical Support: 800-282-9855 Toll Free USA/Canada.

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semic onductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Power Switch ICs - Power Distribution category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

TCK111G,LF(S_FPF1018_DS1222_TCK2065G,LF_SZNCP3712ASNT3G_MIC2033-05BYMT-T5_MIC2033-12AYMT-T5_MIC2033-05BYM6-T5_SLG5NT1437VTR_SZNCP3712ASNT1G_DML1008LDS-7_KTS1670EDA-TR_KTS1640QGDV-TR_KTS1641QGDV-TR NCV459MNWTBG_FPF2260ATMX_U6513A_MIC2012YM-TR_NCP45780IMN24RTWG_AP22953CW12-7_MAX14919AUP+T MAX14919ATP+_KTS1697AEOAB-TR_TCK207AN,LF_BD2227G-LBTR_TCK126BG,LF_XC8111AA010R-G_MPQ5072GG-AEC1-P TCK128BG,LF_XC8110AA018R-G_XC8110AA010R-G_XC8111AA018R-G_MC33882PEP_TPS2104DBVR_MIC2098-1YMT-TR MIC94062YMT_TR_MP6231DN-LF_MIC2015-1.2YM6_TR_MIC2075-2YM_MIC94068YML-TR_SIP32461DB-T2-GE1_NCP335FCT2G TCK105G,LF(S_AP2411S-13_AP2151DSG-13_AP2172MPG-13_MIC94094YC6-TR_MIC94093YC6-TR_MIC94064YC6-TR MIC94061YMT-TR